MOSFET - Power, Single, P-Channel, SOT-23 -60 V, -211 mA

Features

- Trench Technology
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Small Signal Load Switch
- Analog Switch

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Param	Symbol	Value	Unit		
Drain-to-Source Voltage	V _{DSS}	-60	V		
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady	T _A = 25°C	I _D	-196	mA
Current (Note 1)	State	T _A = 85°C		-141	
	t ≤ 5 s	T _A = 25°C		-211	
		T _A = 85°C		-152	
Power Dissipation (Note 1)	Steady State T _A = 25°C		P _D	347	mW
	t ≤ 5 s			403	
Pulsed Drain Current	t _p =	= 10 μs	I _{DM}	-784	mA
Operating Junction and S	T _J , T _{stg}	–55 to 150	°C		
Source Current (Body Diode) (Note 2)			Is	-347	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	360	°C/W
Junction-to-Ambient - t ≤ 5 s (Note 1)	$R_{\theta JA}$	310	°C/W

- 1. Surface-mounted on FR4 board using 1 in. sq. pad size (Cu area 1.127 in. sq. [2 oz.] including traces).
- 2. Surface-mounted on FR4 board using the minimum recommended pad size of 30 mm2, 2 oz. Cu pad.

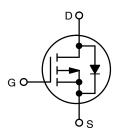


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
-60 V	5 Ω @ –10 V	−211 mA
	6 Ω @ -4.5 V	

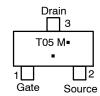
P-Channel





SOT-23 **CASE 318** STYLE 21

MARKING DIAGRAM/ PIN ASSIGNMENT



T05 = Device Code Μ = Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NTR5105PT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
OFF CHARACTERISTICS	<u>. </u>			-	-	-	-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	Reference to 25	°C, I _D = -250 μA		6.5		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25°C			-1.0	μΑ
		$V_{DS} = -60 \text{ V}$	T _J = 125°C			-10	1
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V	_{GS} = ±20 V			± 100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$,	_D = -250 μA	-1.0		-3.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				4.2		mV/°C
Drain-to-Source On-Resistance	R _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -100 \text{ mA}$ $V_{GS} = -4.5 \text{ V}, I_D = -100 \text{ mA}$			1.6	5.0	Ω
					2.2	6.0	1
Forward Transconductance	9FS	$V_{DS} = -5.0 \text{ V}, I_D = -100 \text{ mA}$			227		mS
CHARGES, CAPACITANCES & GATE	RESISTANCE	=			•		
Input Capacitance	C _{iss}				30.3		pF
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V, f} = 1.0 \text{ MHz,}$ $V_{DS} = -25 \text{ V}$			4.7		7
Reverse Transfer Capacitance	C _{rss}				3.2		1
Total Gate Charge	Q _{G(TOT)}				1.0		nC
Threshold Gate Charge	Q _{G(TH)}	$V_{GS} = -5 V, V$	√ _{DS} = −25 V,		0.2		1
Gate-to-Source Charge	Q_{GS}	$I_D = -1$	00 mA		0.4		1
Gate-to-Drain Charge	Q_{GD}				0.3		1
SWITCHING CHARACTERISTICS (No	ote 4)						
Turn-On Delay Time	t _{d(on)}				5.8		ns
Rise Time	t _r	V_{GS} = -5 V, V_{DD} = -48 V, I_{D} = -100 mA, R_{G} = 1 Ω			4.0		1
Turn-Off Delay Time	t _{d(off)}				8.8		1
Fall Time	t _f				12.8		
DRAIN-SOURCE DIODE CHARACTE	RISTICS						
Forward Diode Voltage	V_{SD}	V _{GS} = 0 V,	T _J = 25°C		0.78	1.0	V
		$I_{S} = -100 \text{ mA}$ $T_{J} = 125^{\circ}\text{C}$			0.59		1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

4. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

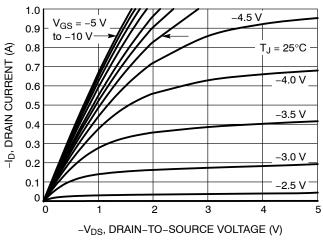


Figure 1. On-Region Characteristics

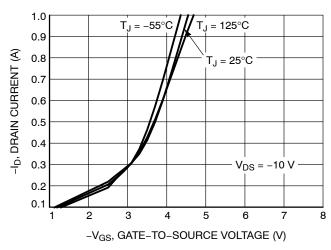


Figure 2. Transfer Characteristics

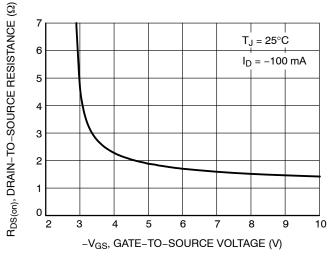


Figure 3. On-Resistance vs. Gate-to-Source Voltage

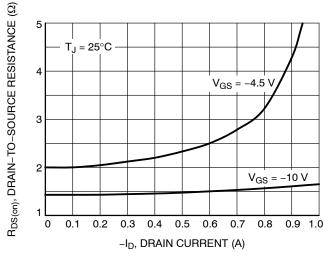


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

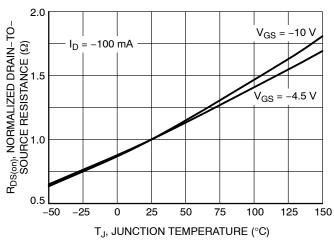


Figure 5. On–Resistance Variation with Temperature

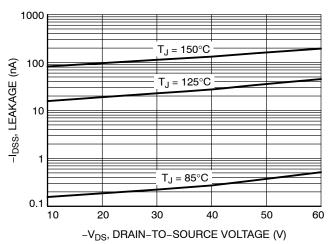


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS

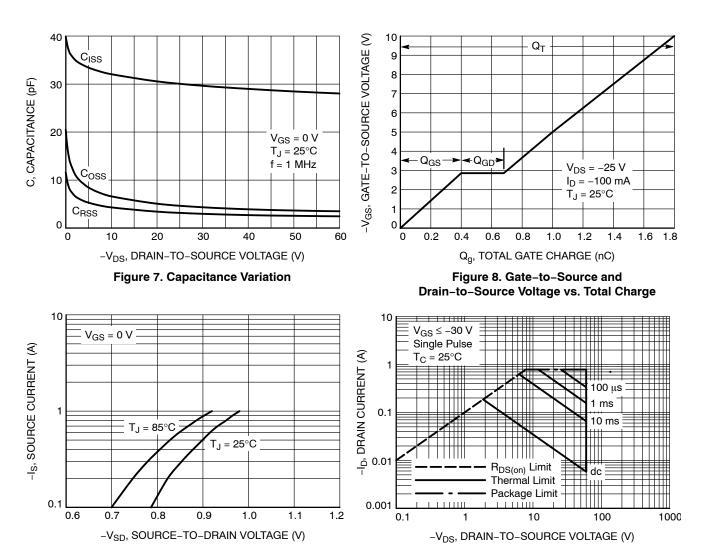


Figure 9. Diode Forward Voltage vs. Current

Figure 10. Maximum Rated Forward Biased Safe Operating Area

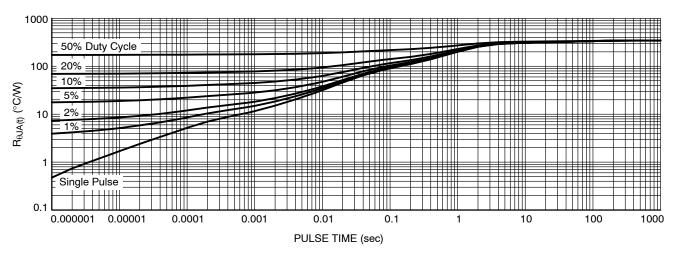


Figure 11. Thermal Response

MILLIMETERS

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40





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MAX

1.11

0.10

0.50

0.20

3.04

1.40

2.04

0.55

0.69

2.64

10°

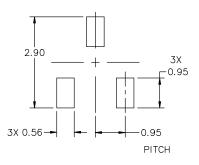




DETAIL "A" Scale 3:1







NOTES:

DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR			
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	2. CATHODE 2.	2: STYLE 13: CATHODE PIN 1. SOURCE CATHODE 2. DRAIN ANODE 3. GATE	STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	2. ANODE 2.	3: STYLE 19: NO CONNECTION PIN 1. CATHODE CATHODE 2. ANODE ANODE 3. CATHODE-ANODE	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT			STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE			

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